

BUK9214-30A

N-channel TrenchMOS logic level FET Rev. 3 — 14 June 2012

Product data sheet

1. **Product profile**

1.1 General description

Logic level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product has been designed and qualified to the appropriate AEC standard for use in automotive critical applications.

1.2 Features and benefits

- Low conduction losses due to low on-state resistance
- Q101 compliant

1.3 Applications

- 12 V loads
- Automotive and general purpose power switching

1.4 Quick reference data

Suitable for logic level gate drive sources

- Suitable for thermally demanding environments due to 175 °C rating
- Motors, lamps and solenoids

Table 1.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C	-	-	30	V
I _D	drain current	V _{GS} = 5 V; T _{mb} = 25 °C; see <u>Figure 1</u> ; see <u>Figure 3</u>	-	-	63	A
P _{tot}	total power dissipation	T _{mb} = 25 °C; see <u>Figure 2</u>	-	-	107	W
Static cha	racteristics					
R _{DSon}	drain-source on-state resistance	V_{GS} = 4.5 V; I_D = 25 A; T_j = 25 °C	-	-	15.5	mΩ
		V_{GS} = 10 V; I_{D} = 25 A; T_{j} = 25 °C	-	9	12	mΩ
		V _{GS} = 5 V; I _D = 25 A; T _j = 25 °C; see <u>Figure 11</u> ; see <u>Figure 12</u>	-	- 11	14	mΩ
Dynamic	characteristics					
Q _{GD}	gate-drain charge	V _{GS} = 5 V; I _D = 25 A; V _{DS} = 24 V; T _j = 25 °C; see <u>Figure 13</u>	-	12.2	-	nC
Avalanch	e ruggedness					
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	I _D = 63 A; V _{sup} ≤ 30 V; R _{GS} = 50 Ω; V _{GS} = 5 V; T _{j(init)} = 25 °C; unclamped	-	-	230	mJ

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2. Pinning information

Table 2.	Pinning	information				
Pin	Symbol	Description	Simplified outline	Graphic symbol		
1	G	gate		_		
2	D	drain	mb			
3	S	source				
mb	D	mounting base; connected to drain		mbb076 S		
			SOT428 (DPAK)			

3. Ordering information

Type number	Package		
	Name	Description	Version
BUK9214-30A	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428

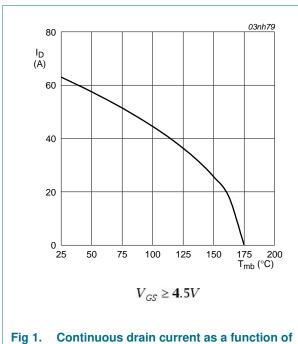
Table 4. Marking codes	
Type number	Marking code
BUK9214-30A	BUK9214-30A

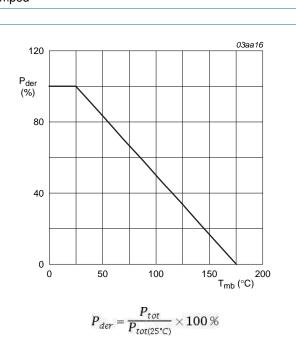
Limiting values 5.

Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C	-	30	V
V _{DGR}	drain-gate voltage	$R_{GS} = 20 \text{ k}\Omega$	-	30	V
V _{GS}	gate-source voltage		-15	15	V
I _D	drain current	T_{mb} = 25 °C; V_{GS} = 5 V; see <u>Figure 1</u> ; see <u>Figure 3</u>	-	63	А
		T_{mb} = 100 °C; V_{GS} = 5 V; see <u>Figure 1</u>	-	45	А
I _{DM}	peak drain current	T_{mb} = 25 °C; pulsed; $t_p \le 10 \ \mu s$; see Figure 3	-	253	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; see <u>Figure 2</u>	-	107	W
T _{stg}	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C
Source-di	rain diode				
ls	source current	T _{mb} = 25 °C	-	63	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$	-	253	А
Avalanch	e ruggedness				
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$\label{eq:ld} \begin{array}{l} I_D = 63 \text{ A}; \ V_{sup} \leq 30 \text{ V}; \ R_{GS} = 50 \ \Omega; \ V_{GS} = 5 \text{ V}; \\ T_{j(\text{init})} = 25 \ ^\circ\text{C}; \ \text{unclamped} \end{array}$	-	230	mJ



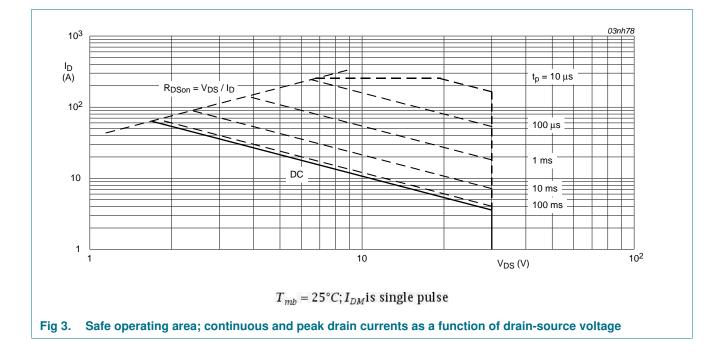




mounting base temperature



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6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	see Figure 4	-	-	1.4	K/W
R _{th(j-a)}	thermal resistance from junction to ambient		-	71.4	-	K/W

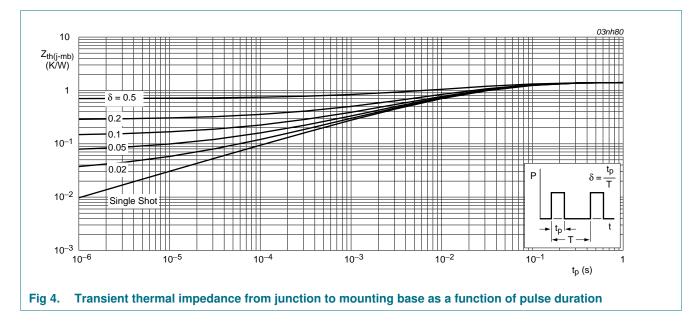
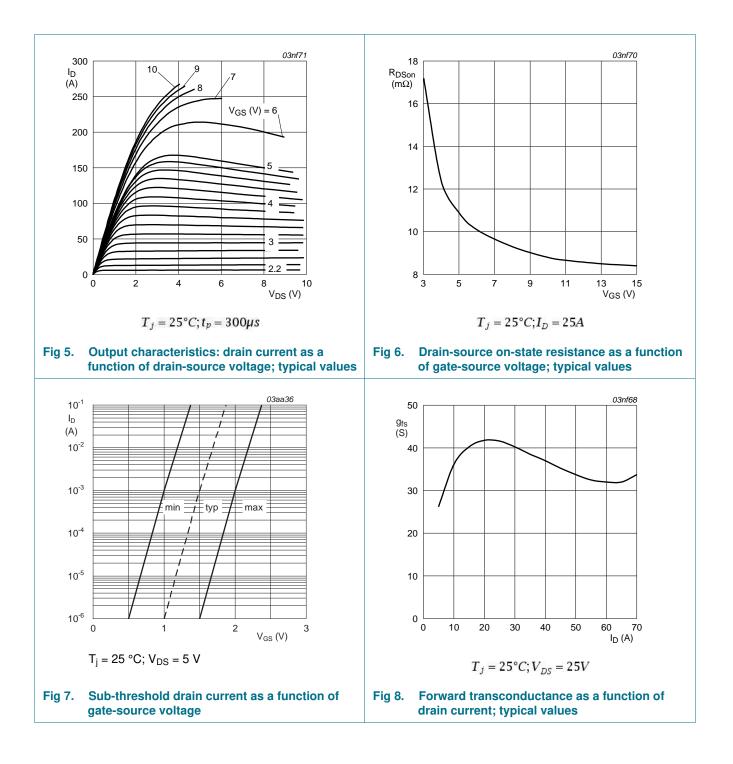


Table 6. Thermal characteristics

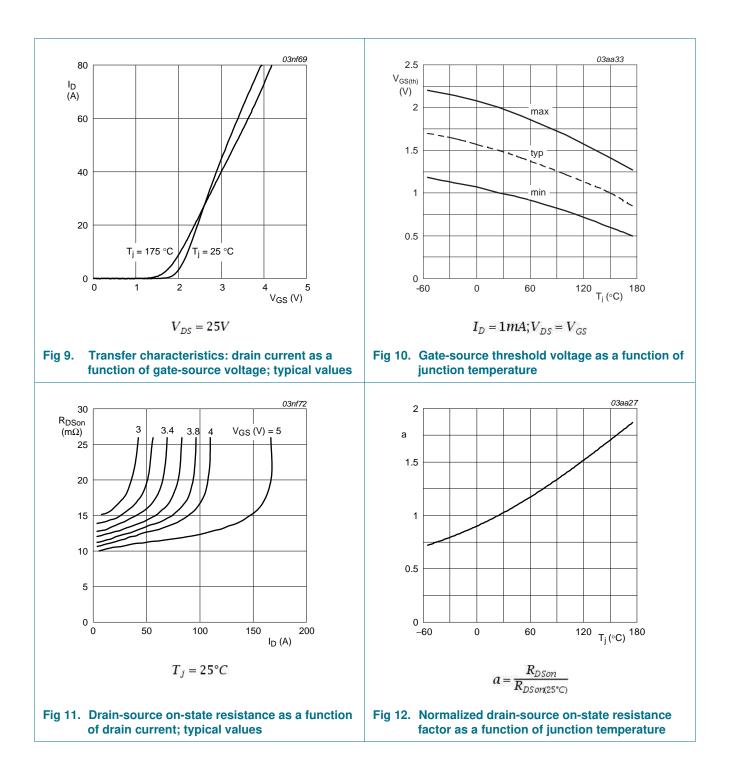
7. Characteristics

Table 7.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
V _{(BR)DSS}	drain-source breakdown	$I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	30	-	-	V
	voltage	$I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{ V}; T_j = -55 \text{ °C}$	27	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA; } V_{DS} = V_{GS}; T_j = 25 \text{ °C};$ see <u>Figure 10</u>	1	1.5	2	V
		$I_D = 1 \text{ mA; } V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ see <u>Figure 10</u>	-	-	2.3	V
		$I_{D} = 1 \text{ mA}; V_{DS} = V_{GS}; T_{j} = 175 \text{ °C};$ see <u>Figure 10</u>	0.5	-	-	V
I _{DSS}	drain leakage current	$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 175 \text{ °C}$	-	-	500	μA
		$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	0.05	10	μA
I _{GSS}	gate leakage current	V_{GS} = 10 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
		V_{GS} = -10 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state	V_{GS} = 4.5 V; I _D = 25 A; T _j = 25 °C	-	-	15.5	mΩ
res	resistance	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ °C}$	-	9	12	mΩ
		$V_{GS} = 5 V$; $I_D = 25 A$; $T_j = 175 °C$; see <u>Figure 11</u> ; see <u>Figure 12</u>	-	-	26.6	mΩ
		$V_{GS} = 5 V$; $I_D = 25 A$; $T_j = 25 °C$; see Figure 11; see Figure 12	-	11	14	mΩ
Dynamic	characteristics					
Q _{G(tot)}	total gate charge	$I_D = 25 \text{ A}; V_{DS} = 24 \text{ V}; V_{GS} = 5 \text{ V};$	-	31	-	nC
Q _{GS}	gate-source charge	T _j = 25 °C; see <u>Figure 13</u>	-	5.3	-	nC
Q _{GD}	gate-drain charge		-	12.2	-	nC
C _{iss}	input capacitance	$V_{GS} = 0 V; V_{DS} = 25 V; f = 1 MHz;$	-	1730	2317	pF
C _{oss}	output capacitance	T _j = 25 °C; see <u>Figure 14</u>	-	400	481	pF
C _{rss}	reverse transfer capacitance		-	260	365	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 30 \text{ V}; \text{ R}_{L} = 1.2 \ \Omega; \text{ V}_{GS} = 5 \text{ V};$	-	10	-	ns
t _r	rise time	$R_{G(ext)} = 10 \ \Omega; T_j = 25 \ ^{\circ}C$	-	85	-	ns
t _{d(off)}	turn-off delay time		-	94	-	ns
t _f	fall time		-	108	-	ns
L _D	internal drain inductance	from drain to centre of die ; $T_j = 25 \text{ °C}$	-	2.5	-	nH
L _S	internal source inductance	from source lead to source bond pad ; $T_j = 25 \text{ °C}$	-	7.5	-	nH
Source-d	rain diode					
V_{SD}	source-drain voltage	I _S = 20 A; V _{GS} = 0 V; T _j = 25 °C; see <u>Figure 15</u>	-	0.85	1.2	V
t _{rr}	reverse recovery time	$I_{S} = 20 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s};$	-	83	-	ns
Q _r	recovered charge	V _{GS} = -10 V; V _{DS} = 30 V; T _i = 25 °C	_	119	-	nC

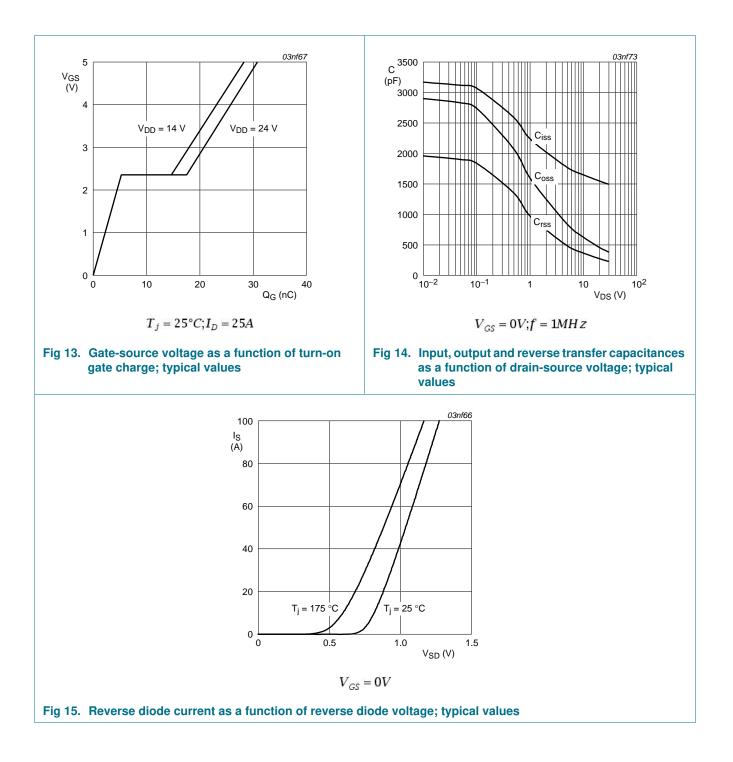
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8. Package outline

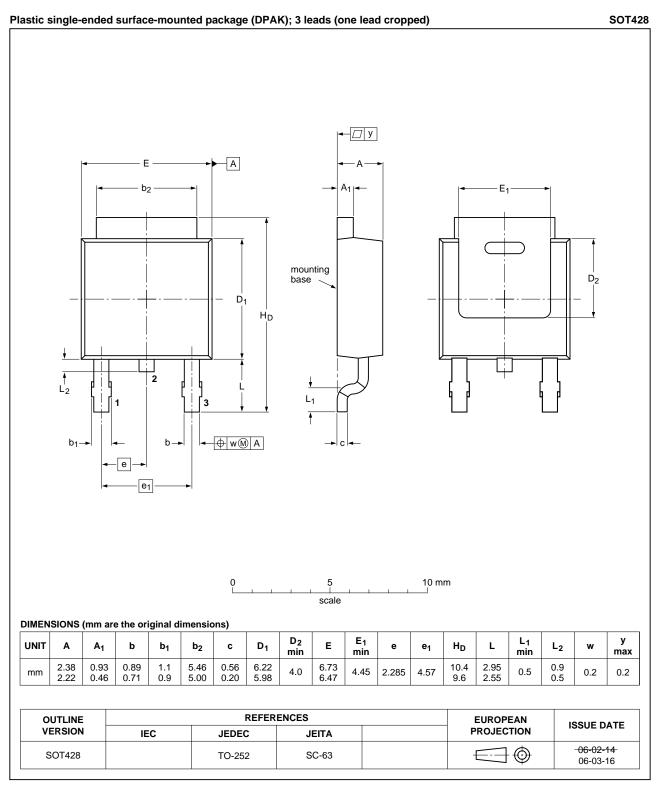


Fig 16. Package outline SOT428 (DPAK)

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9. Revision history

Table 8. Revision I	history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BUK9214-30A v.3	20120614	Product data sheet	-	BUK9214-30A v.2
Modifications:	 Various change 	es to content.		
BUK9214-30A v.2	20100615	Product data sheet	-	BUK9214-30A v.1

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10.1 Data sheet status

Document status ^[1] [2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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